

# **Phase Control Thyristors** (Hockey PUK Version), 650 A



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PRODUCT SUMMARY					
Package	TO-200AC (B-PUK)				
Diode variation	Single SCR				
I <sub>T(AV)</sub>	650 A				
V <sub>DRM</sub> /V <sub>RRM</sub>	400 V, 800 V, 1200 V, 1400 V, 1600 V, 1800 V, 2000 V				
$V_{TM}$	1.90 V				
I <sub>GT</sub>	100 mA				
T <sub>J</sub>	-40 °C to 125 °C				

#### **FEATURES**

- · Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)
- High profile hockey PUK
- · Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### **TYPICAL APPLICATIONS**

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		650	A		
I <sub>T(AV)</sub>	T <sub>hs</sub>	55	°C		
I <sub>T(RMS)</sub>		1230	A		
	T <sub>hs</sub>	25	°C		
I <sub>TSM</sub>	50 Hz	9000	A		
	60 Hz	9420	A		
l <sup>2</sup> t	50 Hz	405	kA <sup>2</sup> s		
	60 Hz	370	KA-S		
V <sub>DRM</sub> /V <sub>RRM</sub>		400 to 2000	V		
t <sub>q</sub>	Typical	100	μs		
T <sub>J</sub>		-40 to 125	°C		

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} I_{DRM}/I_{RRM} MAXIMUM \\ ATT_J = T_J \\ MAXIMUM mA \end{aligned}$			
	04	400	500				
	08	800	900				
	12	1200	1300				
VS-ST330CL	14	1400	1500	50			
	16	1600	1700				
	18	1800	1900				
	20	2000	2100				

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL		TEST CONDITIONS			UNITS	
Maximum average on-state current	-	180° condu	ction, half sine	wave	650 (314)	Α	
at heatsink temperature	I <sub>T(AV)</sub>	double side	(single side) co	oled	55 (75)	°C	
Maximum RMS on-state current	I <sub>T(RMS)</sub>	DC at 25 °C	heatsink tempe	erature double side cooled	1230		
		t = 10 ms	No voltage		9000		
Maximum peak, one-cycle	I	t = 8.3  ms	reapplied		9420	A kA <sup>2</sup> s	
non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		7570		
		t = 8.3 ms	reapplied	Sinusoidal half wave,	7920		
		t = 10 ms	No voltage reapplied	initial $T_J = T_J$ maximum	405		
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 8.3  ms			370		
Maximum i-t for fusing		t = 10 ms			287		
		t = 8.3 ms	reapplied		262		
Maximum I <sup>2</sup> √t for fusing	I²√t	t = 0.1 to 10	ms, no voltage	e reapplied	4050	kA²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$ , $T_J = T_J$ maximum	0.91	V	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)})$	), $T_J = T_J$ maxin	num	0.93	V	
Low level value of on-state slope resistance	r <sub>t1</sub>	(16.7 % x π	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum			mΩ	
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.57	11152	
Maximum on-state voltage	$V_{TM}$	$I_{pk} = 1730 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.90	V	
Maximum holding current	I <sub>H</sub>	T 25 °C	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load		600	mΛ	
Typical latching current	ΙL	1J = 25 C,	arioue supply 1	Z v resistive idad	1000	mA	

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs			
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}, T_J = 25 °C$	1.0	110			
Typical turn-off time	t <sub>q</sub>	$I_{TM}$ = 550 A, $T_J$ = $T_J$ maximum, dl/dt = 40 A/ $\mu$ s, $V_R$ = 50 V, dV/dt = 20 V/ $\mu$ s, gate 0 V 100 $\Omega$ , $t_p$ = 500 $\mu$ s	100	μs			

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	T <sub>J</sub> = T <sub>J</sub> maximum linear to 80 % rated V <sub>DRM</sub>	500	V/µs
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	50	mA



TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	
PANAMETEN	STWIDOL	I Ex	ST CONDITIONS	Тур.	Max.	UNITS
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10	0.0	W
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	3	.0	Α
Maximum peak positive gate voltage	+ V <sub>GM</sub>	T - T maximum	+ < 5 mg	20		V
Maximum peak negative gate voltage	- V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms			5.0	
		T <sub>J</sub> = -40 °C	Maximum required gate trigger/	200	-	
DC gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = 25 °C		100	200	mA
		T <sub>J</sub> = 125 °C		50	-	
		T <sub>J</sub> = -40 °C	current/voltage are the lowest value which will trigger all units	2.5	-	
DC gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	12 V anode to cathode applied	1.8	3.0	V
		T <sub>J</sub> = 125 °C		1.1	-	
DC gate current not to trigger	I <sub>GD</sub>	T. T. markima	Maximum gate current/voltage not to trigger is the maximum	1	0	mA
DC gate voltage not to trigger	$V_{GD}$	$T_J = T_J$ maximum	value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	0.25		V

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction temperature range	TJ		-40 to 125	· °C		
Maximum storage temperature range	T <sub>Stg</sub>		-40 to 150			
Maximum thermal resistance, junction to heatsink	D	DC operation single side cooled	0.11			
	R <sub>thJ-hs</sub>	DC operation double side cooled	0.06	K/W		
Martin and harmal and the second and the	R <sub>thC-hs</sub>	DC operation single side cooled	0.011			
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.005			
Mounting force, ± 10 %			9800 (1000)	N (kg)		
Approximate weight			250	g		
Case style		See dimensions - link at the end of datasheet	TO-200AC (	B-PUK)		

△R <sub>thJ-hs</sub> CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL	CONDUCTION	NDUCTION RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS	
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS	
180°	0.012	0.010	0.008	0.008			
120°	0.014	0.015	0.014	0.014	]		
90°	0.018	0.018	0.019	0.019	$T_J = T_J$ maximum	K/W	
60°	0.026	0.027	0.027	0.028			
30°	0.045	0.046	0.046	0.046			

#### Note

• The table above shows the increment of thermal resistance R<sub>thJ-hs</sub> when devices operate at different conduction angles than DC

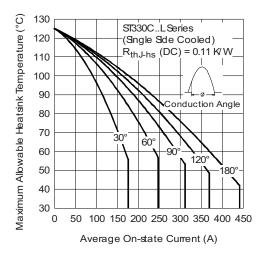


Fig. 1 - Current Ratings Characteristics

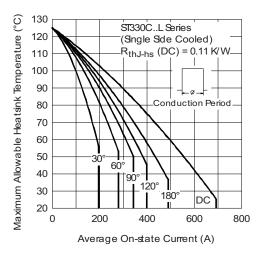


Fig. 2 - Current Ratings Characteristics

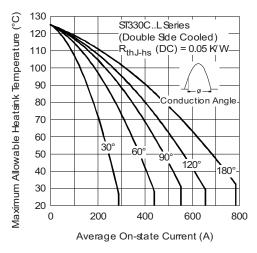


Fig. 3 - Current Ratings Characteristics

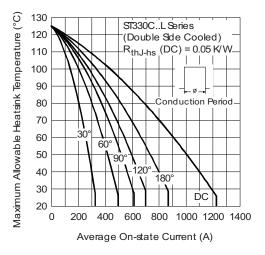


Fig. 4 - Current Ratings Characteristics

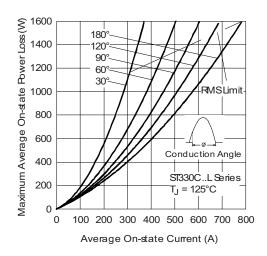


Fig. 5 - On-State Power Loss Characteristics

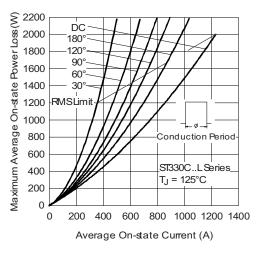


Fig. 6 - On-State Power Loss Characteristics

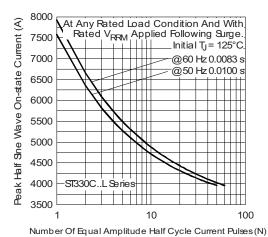


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

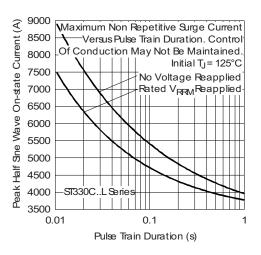


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

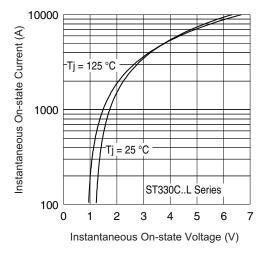


Fig. 9 - On-State Voltage Drop Characteristics

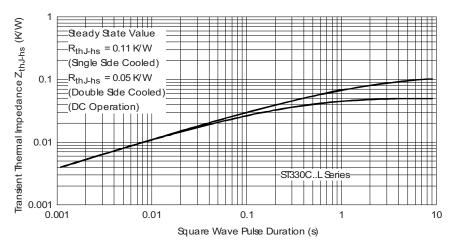


Fig. 10 - Thermal Impedance  $Z_{thJ-hs}$  Characteristics

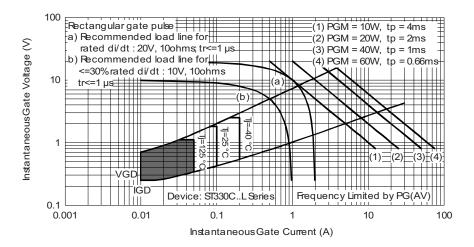


Fig. 11 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**

**Device code** ST VS-33 0 C 16 1 L (2) (3)4 8 5 6 Vishay Semiconductors product **Thyristor** Essential part number 0 = Converter grade C = Ceramic PUK Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table) L = PUK case TO-200AC (B-PUK) 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads) 1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads) 2 = Eyelet terminals (gate and auxiliary cathode soldered leads) 3 = Fast-on terminals (gate and auxiliary cathode soldered leads) 9 Critical dV/dt: • None = 500 V/µs (standard selection)

LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95076

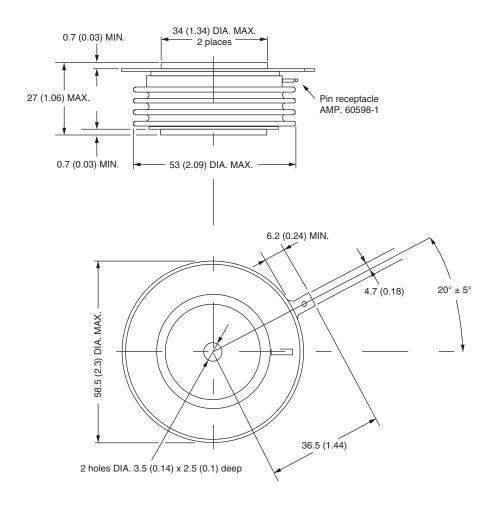
• L = 1000 V/µs (special selection)



# **TO-200AC (B-PUK)**

#### **DIMENSIONS** in millimeters (inches)

Creepage distance: 36.33 (1.430) minimum Strike distance: 17.43 (0.686) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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